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# FDMC4435BZ

## P-Channel Power Trench<sup>®</sup> MOSFET

-30 V, -18 A, 20 mΩ

### Features

- Max  $r_{DS(on)}$  = 20 mΩ at  $V_{GS} = -10$  V,  $I_D = -8.5$  A
- Max  $r_{DS(on)}$  = 37 mΩ at  $V_{GS} = -4.5$  V,  $I_D = -6.3$  A
- Extended  $V_{GSS}$  range (-25 V) for battery applications
- High performance trench technology for extremely low  $r_{DS(on)}$
- High power and current handling capability
- HBM ESD protection level >7 kV typical (Note 4)
- 100% UIL Tested
- Termination is Lead-free and RoHS Compliant

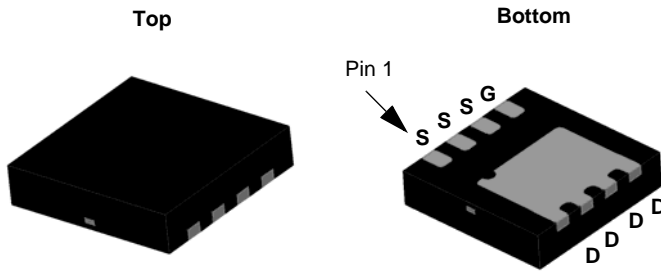


### General Description

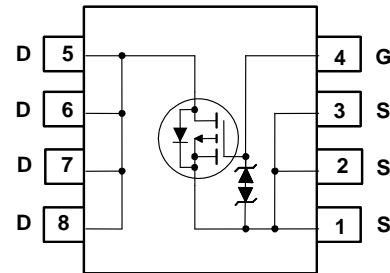
This P-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench<sup>®</sup> process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

### Applications

- High side in DC - DC Buck Converters
- Notebook battery power management
- Load switch in Notebook



MLP 3.3x3.3



### MOSFET Maximum Ratings $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Conditions	Rated Value	Units
$V_{DS}$	Drain to Source Voltage		-30	V
$V_{GS}$	Gate to Source Voltage		±25	V
$I_D$	Drain Current -Continuous	$T_C = 25$ °C	-18	A
	-Continuous	$T_A = 25$ °C (Note 1a)	-8.5	
	-Pulsed		-50	
$E_{AS}$	Single Pulse Avalanche Energy	(Note 3)	32	mJ
$P_D$	Power Dissipation	$T_C = 25$ °C	31	W
	Power Dissipation	$T_A = 25$ °C (Note 1a)	2.3	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range		-55 to +150	°C

### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case		4	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	53	

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC4435BZ	FDMC4435BZ	MLP 3.3X3.3	13 "	12 mm	3000 units

## Electrical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = -250\ \mu\text{A}, V_{GS} = 0\ \text{V}$	-30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250\ \mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		21		mV/ $^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = -24\ \text{V},$ $V_{GS} = 0\ \text{V},$ $T_J = 125\text{ }^\circ\text{C}$			-1 -100	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 25\ \text{V}, V_{DS} = 0\ \text{V}$			$\pm 10$	$\mu\text{A}$

## On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250\ \mu\text{A}$	-1.0	-1.8	-3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250\ \mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		-5		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = -10\ \text{V}, I_D = -8.5\ \text{A}$		14	20	m $\Omega$
		$V_{GS} = -4.5\ \text{V}, I_D = -6.3\ \text{A}$		21	37	
		$V_{GS} = -10\ \text{V}, I_D = -8.5\ \text{A},$ $T_J = 125\text{ }^\circ\text{C}$		20	29	
$g_{FS}$	Forward Transconductance	$V_{DD} = -5\ \text{V}, I_D = -8.5\ \text{A}$		25		S

## Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = -15\ \text{V}, V_{GS} = 0\ \text{V},$ $f = 1\ \text{MHz}$		1535	2040	pF
$C_{oss}$	Output Capacitance			310	410	pF
$C_{rss}$	Reverse Transfer Capacitance			280	420	pF
$R_g$	Gate Resistance	$f = 1\ \text{MHz}$		4		$\Omega$

## Switching Characteristics

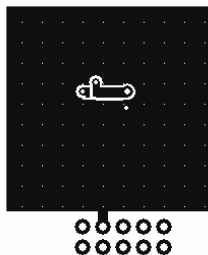
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = -15\ \text{V}, I_D = -8.5\ \text{A},$ $V_{GS} = -10\ \text{V}, R_{GEN} = 6\ \Omega$		10	20	ns	
$t_r$	Rise Time			9	18	ns	
$t_{d(off)}$	Turn-Off Delay Time			35	56	ns	
$t_f$	Fall Time			19	34	ns	
$Q_g$	Total Gate Charge		$V_{GS} = 0\ \text{V to } -10\ \text{V}$		38	53	nC
$Q_g$	Total Gate Charge	$V_{GS} = 0\ \text{V to } -4.5\ \text{V}$	$V_{DD} = -15\ \text{V},$ $I_D = -8.5\ \text{A}$		20	28	nC
$Q_{gs}$	Gate to Source Charge				4.3		nC
$Q_{gd}$	Gate to Drain "Miller" Charge				11		nC

## Drain-Source Diode Characteristics

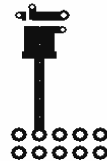
$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{GS} = 0\ \text{V}, I_S = -8.5\ \text{A}$ (Note 2)		0.86	1.5	V
		$V_{GS} = 0\ \text{V}, I_S = -1.9\ \text{A}$ (Note 2)		0.74	1.2	
$t_{rr}$	Reverse Recovery Time	$I_F = -8.5\ \text{A}, di/dt = 100\ \text{A}/\mu\text{s}$		26	40	ns
$Q_{rr}$	Reverse Recovery Charge			12	20	nC

### NOTES:

1.  $R_{\theta JA}$  is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



a. 53  $^\circ\text{C}/\text{W}$  when mounted on a 1 in<sup>2</sup> pad of 2 oz copper



b. 125  $^\circ\text{C}/\text{W}$  when mounted on a minimum pad of 2 oz copper

2. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty cycle < 2.0 %.

3. Starting  $T_J = 25\text{ }^\circ\text{C}$ ; P-ch:  $L = 1\ \text{mH}, I_{AS} = -8\ \text{A}, V_{DD} = -27\ \text{V}, V_{GS} = -10\ \text{V}$ .

4. The diode connected between the gate and source serves only as protection against ESD. No gate overvoltage rating is implied.

**Typical Characteristics**  $T_J = 25^\circ\text{C}$  unless otherwise noted

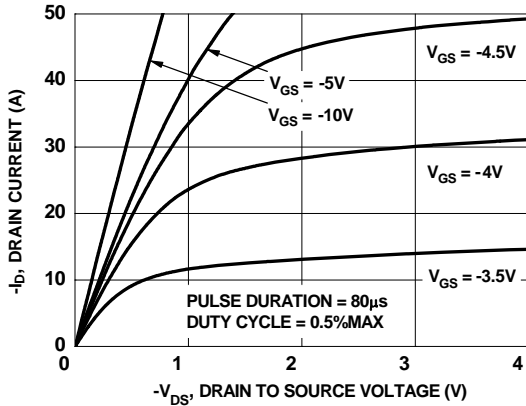


Figure 1. On-Region Characteristics

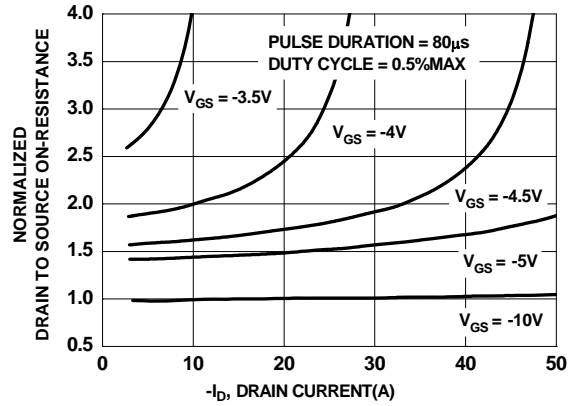


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

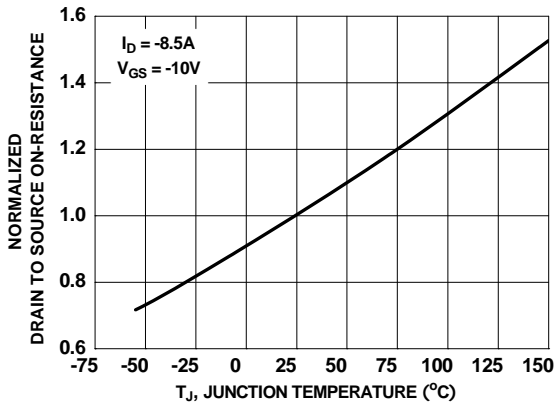


Figure 3. Normalized On-Resistance vs Junction Temperature

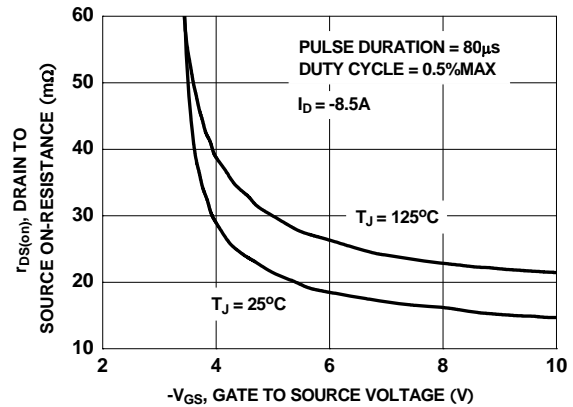


Figure 4. On-Resistance vs Gate to Source Voltage

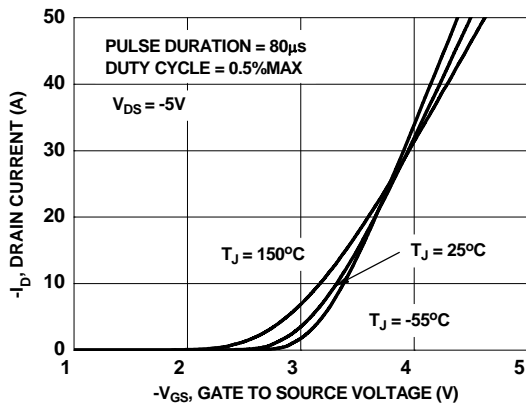


Figure 5. Transfer Characteristics

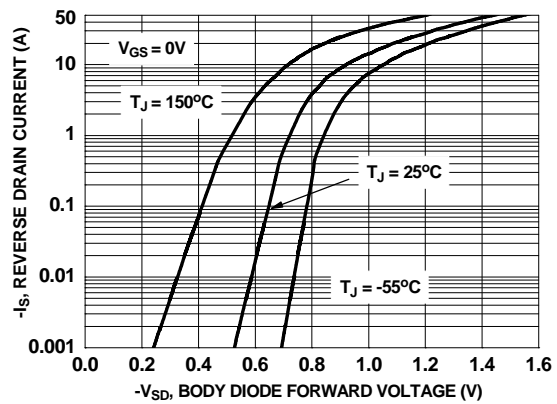
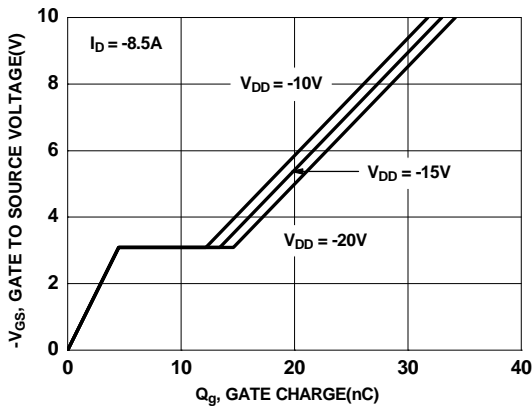
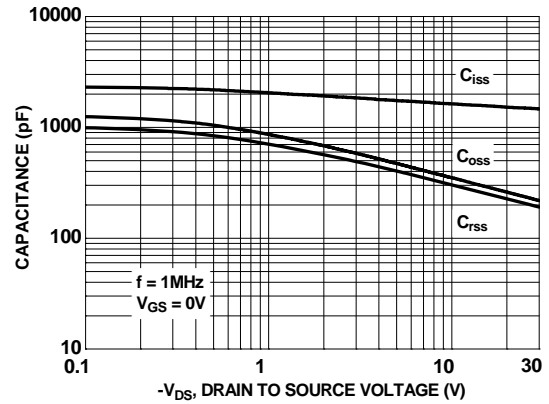


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

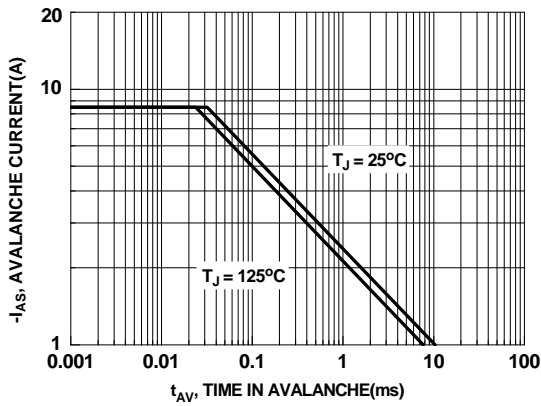
**Typical Characteristics**  $T_J = 25^\circ\text{C}$  unless otherwise noted



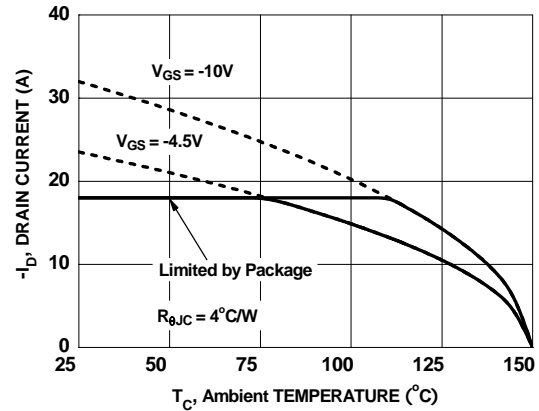
**Figure 7. Gate Charge Characteristics**



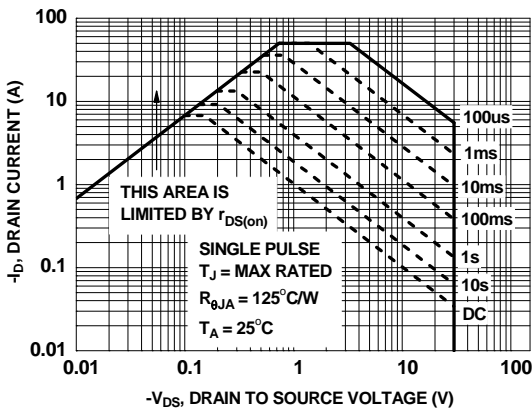
**Figure 8. Capacitance vs Drain to Source Voltage**



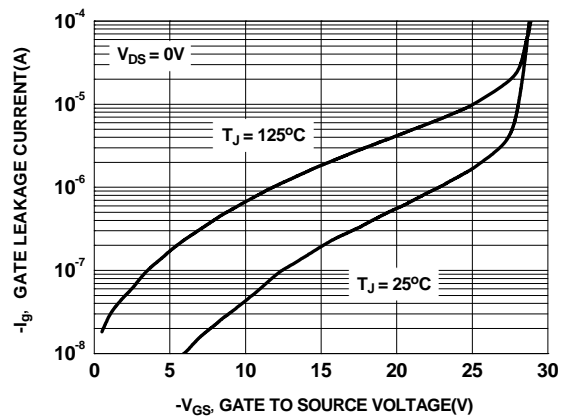
**Figure 9. Unclamped Inductive Switching Capability**



**Figure 10. Maximum Continuous Drain Current vs Case Temperature**



**Figure 11. Forward Bias Safe Operating Area**



**Figure 12. I<sub>gss</sub> vs V<sub>gss</sub>**

**Typical Characteristics**  $T_J = 25^\circ\text{C}$  unless otherwise noted

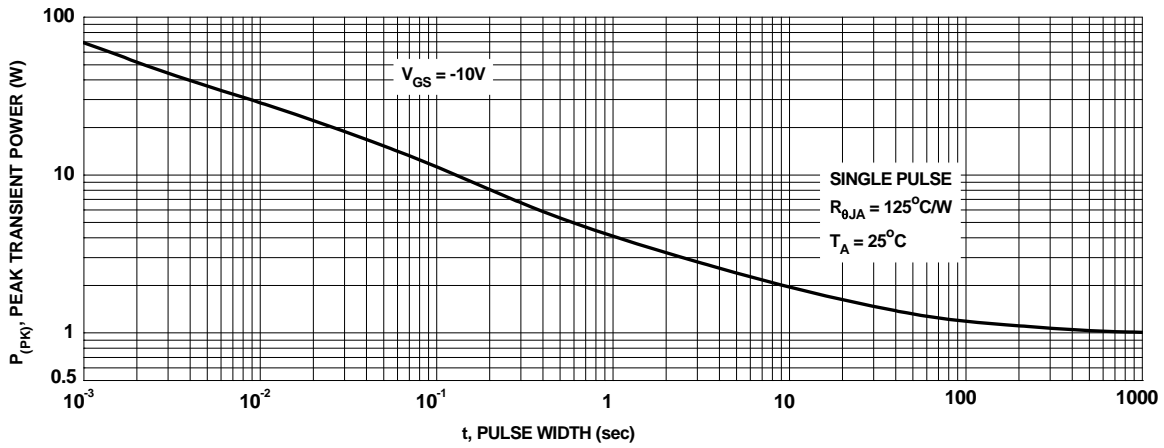


Figure 13. Single Pulse Maximum Power Dissipation

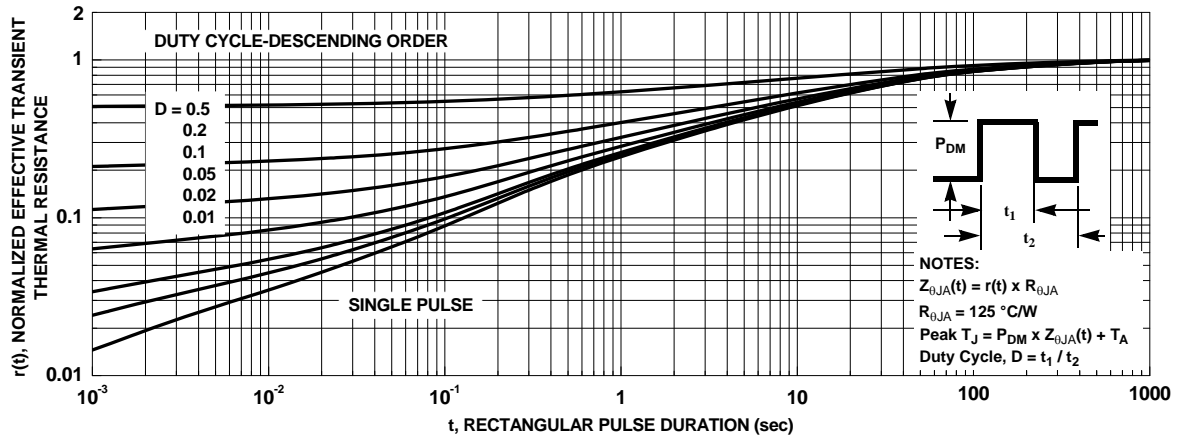
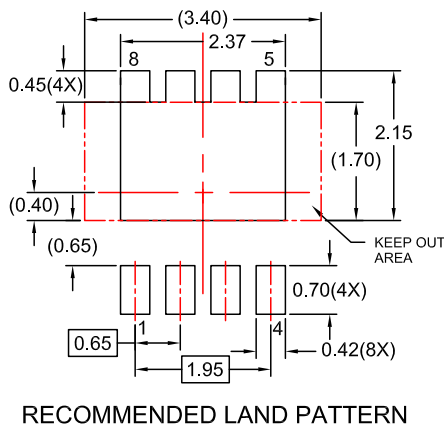
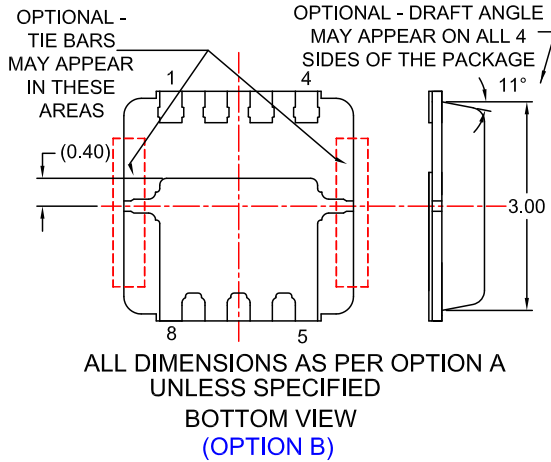
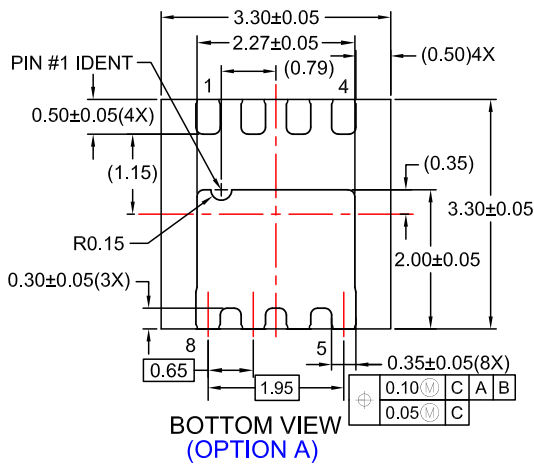
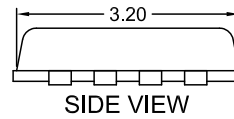
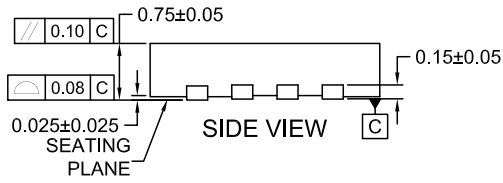
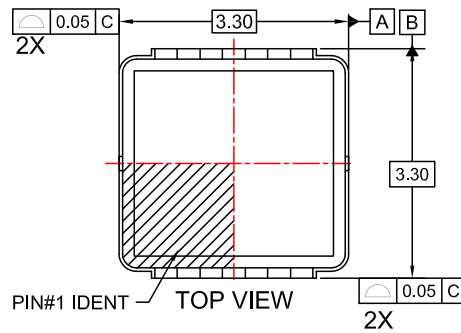
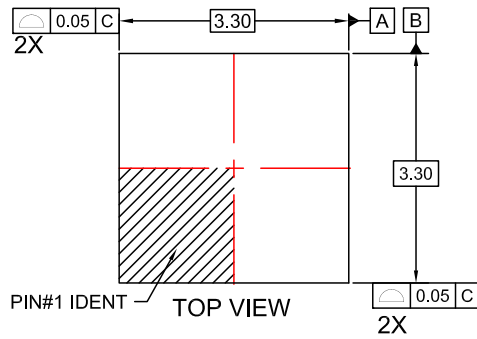
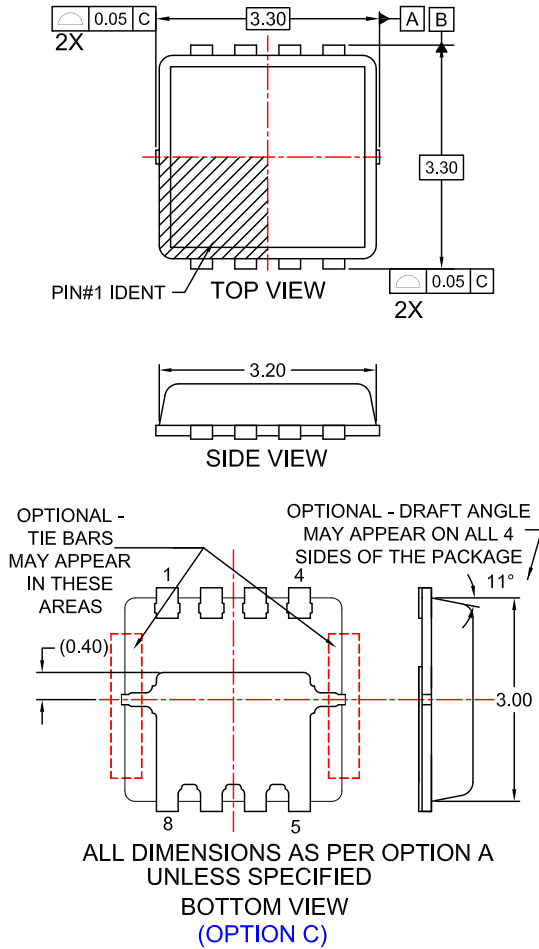


Figure 14. Transient Thermal Response Curve

### Dimensional Outline and Pad Layout



## Dimensional Outline and Pad Layout



### NOTES:

- A. PACKAGE DOES NOT FULLY CONFORM TO JEDEC REGISTRATION MO-240.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN
- E. DIMENSIONS DO NOT INCLUDE BURRS OR MOLD FLASH. BURRS OR MOLD FLASH SHALL NOT EXCEED 0.10MM.
- F. DRAWING FILENAME: MKT-MLP08Wrev3.
- G. OPTION A - SAWN MLP, OPTIONS B & C - PUNCH MLP.



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| AccuPower™                                                                        | F-PFST™                                         | OPTOPLANAR®                                                                       |                                                                                     |
| AttitudeEngine™                                                                   | FRFET®                                          |  |  |
| Awinda®                                                                           | Global Power Resource™                          | Power Supply WebDesigner™                                                         | TinyBoost®                                                                          |
| AX-CAP®*                                                                          | GreenBridge™                                    | PowerTrench®                                                                      | TinyBuck®                                                                           |
| BitSiC™                                                                           | Green FPS™                                      | PowerXS™                                                                          | TinyCalc™                                                                           |
| Build it Now™                                                                     | Green FPS™ e-Series™                            | Programmable Active Droop™                                                        | TinyLogic®                                                                          |
| CorePLUS™                                                                         | Gmax™                                           | QFET®                                                                             | TINYOPTO™                                                                           |
| CorePOWER™                                                                        | GTO™                                            | QS™                                                                               | TinyPower™                                                                          |
| CROSSVOLT™                                                                        | IntelliMAX™                                     | Quiet Series™                                                                     | TinyPWM™                                                                            |
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| Dual Cool™                                                                        | MICROCOUPLER™                                   | SignalWise™                                                                       | TRUECURRENT®*                                                                       |
| EcoSPARK®                                                                         | MicroFET™                                       | SmartMax™                                                                         | μSerDes™                                                                            |
| EfficientMax™                                                                     | MicroPak™                                       | SMART START™                                                                      |  |
| ESBC™                                                                             | MicroPak2™                                      | Solutions for Your Success™                                                       | UHC®                                                                                |
|  | MillerDrive™                                    | SPM®                                                                              | Ultra FRFET™                                                                        |
| Fairchild®                                                                        | MotionMax™                                      | STEALTH™                                                                          | UniFET™                                                                             |
| Fairchild Semiconductor®                                                          | MotionGrid®                                     | SuperFET®                                                                         | VCX™                                                                                |
| FACT Quiet Series™                                                                | MTI®                                            | SuperSOT™-3                                                                       | VisualMax™                                                                          |
| FACT®                                                                             | MTx®                                            | SuperSOT™-6                                                                       | VoltagePlus™                                                                        |
| FastvCore™                                                                        | MVN®                                            | SuperSOT™-8                                                                       | XST™                                                                                |
| FETBench™                                                                         | mWSaver®                                        | SupreMOS®                                                                         | Xsens™                                                                              |
| FPS™                                                                              | OptoHiT™                                        | SyncFET™                                                                          | 仙童®                                                                                 |
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Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
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